

Fermi-surface properties of the perovskite superconductors

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We calculate Fermi-surface properties of the Cuprate superconductors within the three-band Hubbard model using a cluster expansion for the proper self-energy. The Fermi-surface topology is in agreement with angular-resolved photoemission data for dopings 20%. We discuss possible violations of the Luttinger sum-rule for smaller dopings and the role of van-Hove singularities in the density of states of the Zhang-Rice singlets. We calculate the shift in the chemical potential upon doping and find quantitative agreement with recent experiments.

PACS.71.10 Many-body theory { electron states

PACS.74.20 High- T_C { theory

PACS.79.60 Photoemission

Introduction In the last years, the experimental characterization of Fermi-surface properties of the high-temperature superconductors has progressed with the help of angle-resolved^(1;2;3;4;5) and angle-integrated⁽⁶⁾ photoemission studies. The such determined Fermi-surface topology agrees quite well with results from band-structure calculations based on the local-density approximation⁽⁷⁾. This measured Fermi-surface topology has been taken as an input for theoretical calculations⁽⁸⁾ in the so called "Fermiology" scenario. Many theorists use, on the other hand, a simplified three-band Hamiltonian (also called Emery model⁽⁹⁾), which incorporates strong, local correlations, as exemplified by the composite-operator approach⁽¹⁰⁾. Determination of the Fermi-surface properties of the Emery model is of central interest and has been investigated in a series of recent studies^(11;12;13;14).

It is difficult to calculate with numerical methods, like exact diagonalization^(15;16) or Quantum Monte-Carlo⁽¹⁷⁾, the Fermi-surface topology for the three-band model directly, due to cluster-size limitations. The numerical methods have been shown, on the other side, to be very useful for extracting the energy scales of the local charge- and spin excitations⁽¹⁵⁾. Here we propose that the cluster self-energy provides the missing link between such numerical approaches and calculation of momentum-dependent properties, like the Fermi-surface topology.

Method The self-energy of finite clusters with open boundary conditions contains in a very precise way information upon the Green's function and self-energy of the extended system⁽¹⁸⁾. Let us consider the real-space components of the self-energy for both the extended system, $G_{ij}^{(c)}(\omega)$, and for a given finite cluster with open boundary conditions, $G_{ij}^{(c)}(\omega)$. It is straightforward, that all irreducible diagrams contributing to $G_{ij}^{(c)}(\omega)$ are a subset of the diagrams contributing to $G_{ij}^{(c)}(\omega)$. Therefore the cluster self-energy is a systematic approximation to the self-energy of the full system.

Typically one first evaluates the cluster Green's function, $G_{ij}^{(c)}(\omega)$, in an exact diagonalization study. The cluster self-energy is then obtained by inverting the cluster Dyson's equation

$$G_{ij}^{(c)}(\omega) = G_{ij}^{(c;0)}(\omega) + \sum_{m,n} G_{im}^{(c;0)}(\omega) \Sigma_{mn}^{(c)}(\omega) G_{nj}^{(c)}(\omega); \quad (1)$$

where the i, m, n, j are sites of the cluster and $G_{ij}^{(c;0)}(\omega)$ is the non-interacting cluster Green's function.

The Green's function of the full CuO_2 lattice is determined by inserting the $\Sigma_{mn}^{(c)}(\omega)$ determined from Eq. (1), into the Dyson's equation of the extended system

$$G_{ij}(\omega) = G_{ij}^{(0)}(\omega) + \sum_{m,n} G_{im}^{(0)}(\omega) \Sigma_{mn}^{(c)}(\omega) G_{nj}(\omega); \quad (2)$$

where the i, m, n, j run over all sites of the CuO_2 lattice and $G_{ij}^{(0)}(\omega)$ is the non-interacting Green's function of the CuO_2 plane. The Green's function, $G_{ij}(\omega)$, obtained

by Eq. (2) can be systematically improved considering larger and larger clusters in Eq. (1). The smallest cluster one could possibly consider is the one-site-cluster and Eq. (2) together with Eq. (1) would then reduce to the Hubbard-I approximation⁽¹⁹⁾. For the Emery model we consider the CuO_4 cluster for Eq. (1). Within this approximation both the important local charge fluctuations and the singlet-triplet splitting are included.

The passage of the quasi-particle peak through the chemical potential, determined from the k -dependent Green's function, $G_k(\omega) = \frac{1}{L} \sum_{i,j} \exp[ik(R_i - R_j)] G_{ij}(\omega)$ determines then the Fermi-surface. The density of electrons is given by

$$n = \frac{2}{\pi} \sum_k \int_{-\infty}^{\infty} d\omega \left(-\frac{1}{2\pi i} \right) \text{Im} G_k(\omega) n_F(\omega) = 2 \sum_k \int_{-\infty}^{\infty} \frac{d^2k}{(2\pi)^2} Z_k; \quad (3)$$

with $n_F(\omega)$ and Z_k being the Fermi distribution function and the quasiparticle spectral weight respectively. The factor of two in Eq. (3) comes from spin-degeneracy and the k -sum is over all occupied states. The density of electrons, as given by Eq. (3), is to be determined self-consistently⁽¹⁸⁾ as a function of the chemical potential, μ , by demanding it to be equal to the average density of electrons of the CuO_4 cluster, for which $\langle n \rangle$ is determined via Eq. (1).

Results For the three-band Hamiltonian we have chosen (in electron notation), following Eskes and Sawatzky⁽¹⁵⁾, $\epsilon_d = 5.3\text{eV}$ for the difference in oxygen- and copper orbital energies⁽²⁰⁾, $t_{dp} = 1.3\text{eV}$ and $t_{pp} = 0.65\text{eV}$ for the Cu-O and the O-O hopping matrix element respectively and $U_d = 8.8\text{eV}$ for the onsite Coulomb repulsion on the copper site.

From the Green's function of a CuO_4 cluster we have extracted the self-energy and used it as an approximation for the self-energy of the infinite CuO_2 layer, as explained above. In Fig.1 we illustrate typical results for the angle-integrated spectral function and a doping $x = 20\%$. For comparison in Fig.1 (c) the density of states of the non-interacting CuO_2 plane (i.e. with $U_d = 0$) is shown. The bonding-band (mainly copper) is located around 9eV , the antibonding band (mainly oxygen) extends from 3eV to 1eV and the non-bonding oxygen orbitals is in between. For every band the typical 2D logarithmic van-Hove singularity is clearly visible, for the non-bonding band, for instance, it is located at $5.3\text{eV} = 3.1\text{eV}$. In Fig.1 (b) the location and the weight of the peaks of the CuO_4 -cluster Green's function are shown.

The results for the full Green's function of the extended CuO_2 layer are presented in Fig.1 (a). Coherently propagating many-body bands have formed out of the cluster energy-levels⁽¹⁸⁾. The chemical potential lies in the band of Zhang-Rice singlets⁽²¹⁾, separated by a charge-transfer gap of about 1eV from the empty band of copper- d^{10} states. The non-bonding oxygen orbitals and the band of Zhang-Rice triplets are located -3eV to -5.5eV below the Fermi-level.

Van Hove singularities A van Hove singularity can be observed in the band of Zhang-Rice singlets (see Fig.1 (a)). It is tempting to identify this structure with the very

sharp feature observed in recent angle-resolved photoemission experiments⁽⁵⁾ on untwinned $\text{YBa}_2\text{Cu}_3\text{O}_{6.9}$ about 1 eV below the Fermi-surface. Let us note that, contrary to predictions based on a weak-coupling picture, the van Hove singularity in the density of states does not occur at half-filling in our many body calculation. We find that only for relative large dopings, namely of about 38%, the Fermi-surface would be located right at the van Hove singularity. The absence of a van Hove singularity at the Fermi-edge for dopings $x < 0.2$ is consistent with recent NMR experiments⁽²²⁾ and in contrast to a band-structure calculation based on the local density approximation⁽²³⁾. Also we note that these results do not support the recently proposed "van Hove scenario" of cuprate superconductivity⁽²⁴⁾.

Fermi surface In Fig 2 (a) we present the results for the Fermi-surface as a function of doping, $x = 0.01; \dots; 0.70$. Also given are values of the quasiparticle spectral weight, Z_k , along the (1,1) direction at the Fermi edge. In Fig 2 (b) we present, for comparison, the Fermi-surface of the non-interacting CuO_2 layer at various dopings. (0,0) corresponds to the Γ -point.

We find that the Fermi-surface presented in Fig 2 (a) is in agreement with angular resolved photoemission experiments^(1,3) for dopings of about $x \approx 20\%$. The location along the (1,0) | (1,1) lines does also agree quantitatively quite well. Along the (0,0) | (1,1) line the calculated Fermi edge is located at somewhat too large momenta. We note that the quasiparticle spectral weight is reduced by a factor 2 to 5, depending on the doping. For small dopings the calculated Fermi surface expands rapidly, due to the reduced spectral weight, Z_k (compare Eq. (3)) and finally closes completely for $x = 0$ at the (1,1) point. Similar results for the volume of the Fermi-sea as a function of doping has been found by Unger and Fulde⁽¹²⁾ with the projection technique. Note that the data presented in Fig.1 are for a paramagnetic state and are therefore not in contradiction with the notion^(13,25) that in the antiferromagnetic state and dopings of a few percent, the Fermi-surface should take the form of "hole-pockets" centered around $(\pm\pi; \pm\pi)$.

For small interaction strength, in perturbation theory, the Luttinger sum-rule⁽²⁶⁾ is valid. It states, that the volume of the Fermi-sea of the system with interaction should be equal to that of the non-interacting system. Comparing Fig 2 (b) and Fig 2 (a) we note that the volume of the Fermi-sea obtained for $U_d = 8.8\text{eV}$ is larger than the one predicted by the Luttinger sum-rule (i.e. those obtained for $U_d = 0$). E.g. for $x = 20\%$ the difference is 14% of the Brillouin zone. The cluster-expansion for the self-energy used here is best for large interacting strength and it is therefore not so surprising that the results for the Fermi-surface violate the Luttinger sum-rule, which may be expected to hold for small interactions, U_d . Let us note, that for very large dopings the Fermi-surface for both $U_d = 8.8\text{eV}$ and $U_d = 0$ have nearly identical volumes (for $x = 70\%$ they agree within a percent), since the doped charge carriers go predominantly into the oxygen orbitals, which are influenced only indirectly by U_d .

Quantitatively the Luttinger sum-rule can be experimentally verified best by comparison with results from band-structure calculations. The experimentally determined Fermi-surfaces (accuracy⁽⁴⁾: 10-20% of the Brillouin zone) agree quite well with band-structure

calculations⁽⁷⁾. Since, on the other hand, standard band-structure calculations employ only one Slater determinant they necessarily fulfill the Luttinger sum-rule (and yield a $Z_k = 1$).

Chemical potential In Fig.3 we present the shift (relative to half-filling⁽²⁷⁾) in the chemical potential, μ , upon doping, x . For comparison the shift in the chemical potential for the non-interacting CuO_2 plane, μ_0 , is also shown, they differ by about a factor of two. We have included in Fig.3 the data obtained by a recent photoemission study⁽⁶⁾ on $\text{Bi}_2\text{Sr}_2\text{Ca}_{1-x}\text{Y}_x\text{Cu}_2\text{O}_{8+x}$. In order to compare with the experimental results we adjusted our calculated position of the chemical potential for $x = 0$ to the experimental value for $x = 0.01$. Note that, even though the experimental data for $x = 0.01 :: 0.03$ correspond to an insulator state, while we have a metallic state, excluding these points and adjusting at values, e.g., $x = 0.08$, wouldn't change the curves significantly.

We also show in Fig.3 the doping dependence of the renormalized Fermi-velocity, $v_F = v_{F0} m/m^*$. We find, for about $x = 20\%$ doping, an effective mass $m^* = m$ of about two, in agreement with results from angle-resolved photoemission experiments⁽¹⁾ and quantum Monte-Carlo studies⁽¹⁷⁾. The effective mass is found to diverge for dopings $x \rightarrow 0$ (see Fig.3), as a signal of the metal-insulator transition at half-filling.

Conclusions It is still controversial how the Fermi surface of 2D correlated, translational invariant electrons on a lattice changes when going from the metal to the Mott-Hubbard insulator regime as a function of electron density. While it seems clear⁽¹³⁾ that the first holes doped into the half-filled, antiferromagnetic ordered insulator, occupy states with momenta around $(\pi, 2; 2, \pi)$, the situation for finite doping concentrations in the paramagnetic state is not so clear. Here we proposed a scenario, where the volume of the Fermi sea expands continuously with particle density towards the (π, π) point at half-filling.

For moderate dopings, $x \approx 0.2\%$, this scenario is compatible with exact diagonalization results of one-band models⁽²⁵⁾ and angle-resolved photoemission⁽³⁾ experiments on the cuprate superconductors. For small dopings, $x = 5 - 10\%$ we predict deviations from the Luttinger sum-rule, which might be measurable. The calculated shift in chemical potential associated with the Fermi-surface topology is in reasonable agreement with recent photoemission experiments⁽⁶⁾.

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Figure captions

Fig.1 (a) A typical result for the angle-integrated spectral weight, for a doping $x=0.2$. The Fermi surface lies in the band of coherently propagating Zhang-Rice singlets. (b) The position and the weight of the poles of the CuO_4 cluster Green's function used for calculating the self-energy. (c) For comparison the density of states of the non-interacting ($U_d = 0$) CuO_2 plane with the three van Hove singularities for the bonding, non-bonding and the antibonding band.

Fig.2 (a) Results for the position of the Fermi surface in the first Brillouin zone, as a function of doping, x , and the quasiparticle renormalization factor, Z , at the Fermi edge. Note the strong reduction of Z near the $(\pi; \pi)$ point. (b) For comparison the Fermi surface of the non-interacting ($U_d = 0$) CuO_2 plane, which fulfills the Luttinger sum-rule, is shown.

Fig.3 Filled circles: Results for the shift in the chemical potential, μ , upon doping, x , relative to half-filling. Crosses: Experimental⁽⁶⁾ results for the shift in chemical potential for $\text{Bi}_2\text{Sr}_2\text{Ca}_{1-x}\text{Y}_x\text{Cu}_2\text{O}_{8+}$. Open circles: For comparison the shift in μ_0 of the non-interacting, $U_d = 0$, CuO_2 plane. Filled squares: The renormalized Fermi velocity, $v_F = v_{F0} m_0/m$. Note the reduction of about two for $x = 0.2$.